NPN Epitaxial Planar Silicon Transistor



2SD1627

Driver Applications

Applications

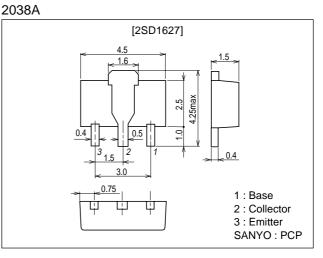
• Motor drivers, hammer drivers, relay drivers, voltage regulator control.

Features

- · High DC current gain ($h_{FE} \ge 4000$).
- · Wide ASO.
- Ultrasmall size making it easy to provide highdensity, small-sized hybrid ICs.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		30	V
Collector-to-Emitter Voltage	VCEO		25	V
Emitter-to-Base Voltage	VEBO		10	V
Collector Current	ι _C		2	A
Collector Current (Pulse)	I _{CP}		3	A
Collector Dissipation	De		500	mW
	PC	Mounted on ceramic board (250mm ² ×0.8mm)	1.5	w
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =20V, I _E =0			1	μA
Emitter Cutoff Current	IEBO	V _{EB} =8V, I _C =0			1	μA
DC Current Gain	h _{FE} 1	V _{CE} =2V, I _C =500mA	4000			
	h _{FE} 2	V _{CE} =2V, I _C =10mA	3000			
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =50mA		120		MHz
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =600mA, I _B =0.15mA		0.9	1.5	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =600mA, I _B =0.15mA			2.0	V
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Marking : DJ

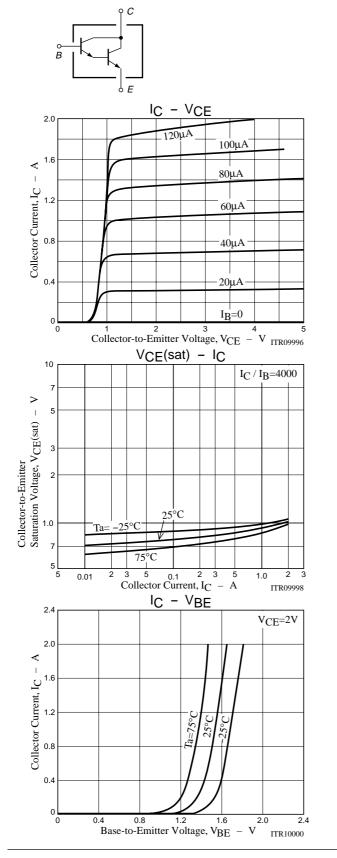
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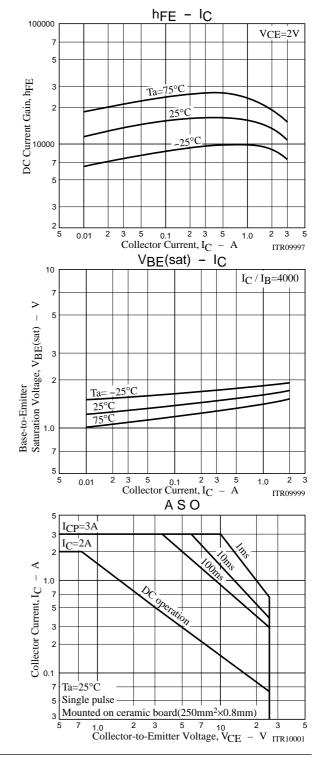
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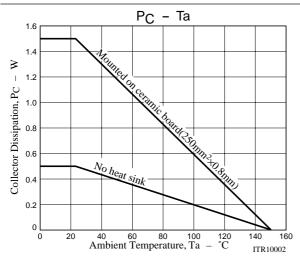
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =10μΑ, I _E =0	30			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =1mA, R _{BE} =∞	25			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	Ι _Ε =10μΑ, Ι _C =0	10			V

Electrical Connection







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